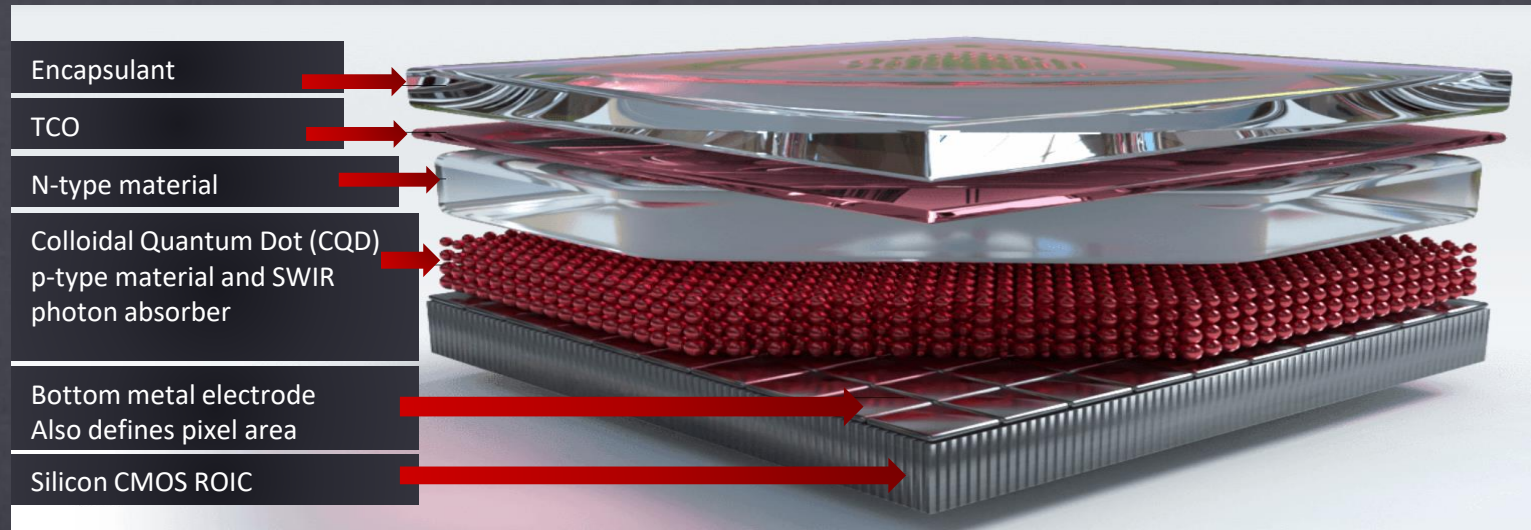




High definition, low cost, CQD sensor technology demonstrated in  
laser marking / designating application(s)

Defense and Commercial Sensing  
May 2023

# Colloidal Quantum Dot CQD<sup>®</sup> Detector Overview



- ✓ Novel SWIR sensor fabrication method. Monolithic fabrication directly on 8" or 12" CMOS ROIC wafers. No flip chip bonding. Low-cost materials.
- ✓ High-resolution - 12MP demonstrated
- ✓ Small pixel pitch - 3 um demonstrated, capable of sub 2 um
- ✓ Simple fabrication process expected to scale to front-side CMOS prices at corresponding scale
- ✓ Low noise. High dark current doubling temperature. Uncooled.
- ✓ Best-in-class uncooled E-SWIR sensitivity
- ✓ Tunable bandgap which can be paired with wavelengths of interest (e.g. 940, 1380, 1550, 2100 nm)
- ✓ Broadband response from ~250 nm to 2.0 um

## Standard SWIR Cameras (-001s)



Acuros CQD SWIR 640  
Acuros CQD SWIR 1280  
Acuros CQD SWIR 1920

## Extended SWIR Cameras (-002s)



Acuros CQD eSWIR 640  
Acuros CQD eSWIR 1280  
Acuros CQD eSWIR 1920

## Laser Inspection SWIR Cameras (-003s)



Acuros CQD SWIR 640L  
Acuros CQD SWIR 1280L  
Acuros CQD SWIR 1920L

400 to 1600nm

## Lasers Inspection Extended SWIR Cameras (-004s)



Acuros CQD eSWIR 640L  
Acuros CQD eSWIR 1280L  
Acuros CQD eSWIR 1920L

350 to 2000nm

# CQD Image Example - DVI

CMOS Visible camera



Acuros 1920 eSWIR camera



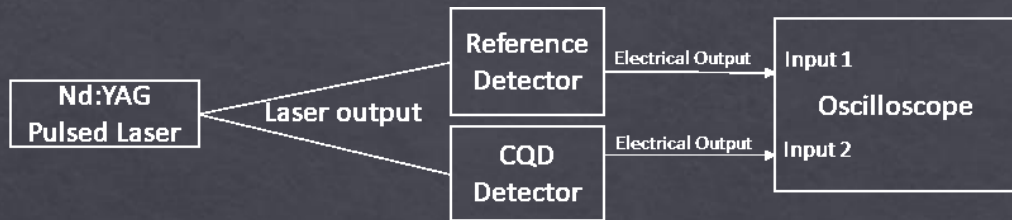
# Why Use CQD Detectors in Laser Pulse Detection (LPD) Systems?

	SWIR Vision CQD		InGaAs		SWIR Vision Advantage
Quantum Efficiency	✗	10-15% in commercial products Demonstrated 50%	✓✓	> 70%	None
Read noise	✓	60e- read noise for 15 um pitch (high gain)	✓	Varies but similar	None
Dark Current at RT	✓	~ 5 nA/cm <sup>2</sup> , 25C	✓	~ 5 nA/cm <sup>2</sup> , 20C	None
Dark Current at the handset and auto operating temps	✓	Doubling temperature = 10.5C Jd (85C) = 190 nA/cm <sup>2</sup> Jd (105C) = 700 nA/cm <sup>2</sup>	✗	Doubling temperature = 7.5C Jd (85C) = 2,000 nA/cm <sup>2</sup> Jd (105C) = 12,000 nA/cm <sup>2</sup>	Lower dark current at elevated operating temps
Pixel Size	✓	Sub- 2μm	✗	Best in class = 5μm < 5μm not expected	Reduced SWAP-C. Enables very high resolution at low cost
Spectral range	✓✓	~ 250 nm – 2.0 um	✓✓	TBD-Expected to be good	Best in class uncooled e-SWIR SNR. e- SWIR more covert
Thermal Reliability	✓	Demonstrating MIL-STD	✓	Fielded	
Volume Scalable	✓	Scaling to 8/12" wafers	✗		Si substrate = large wafers = low cost
Low Cost Scalable	✓✓	Low materials and processes	✗	Does not easily scale to unmounted price requirements	Very low cost. Plans to enter consumer market

CQD detectors are cheaper, smaller, and uncooled eSWIR even more covert

# Are CQD Detectors Fast Enough for LPD Applications?

## Response time measurement setup



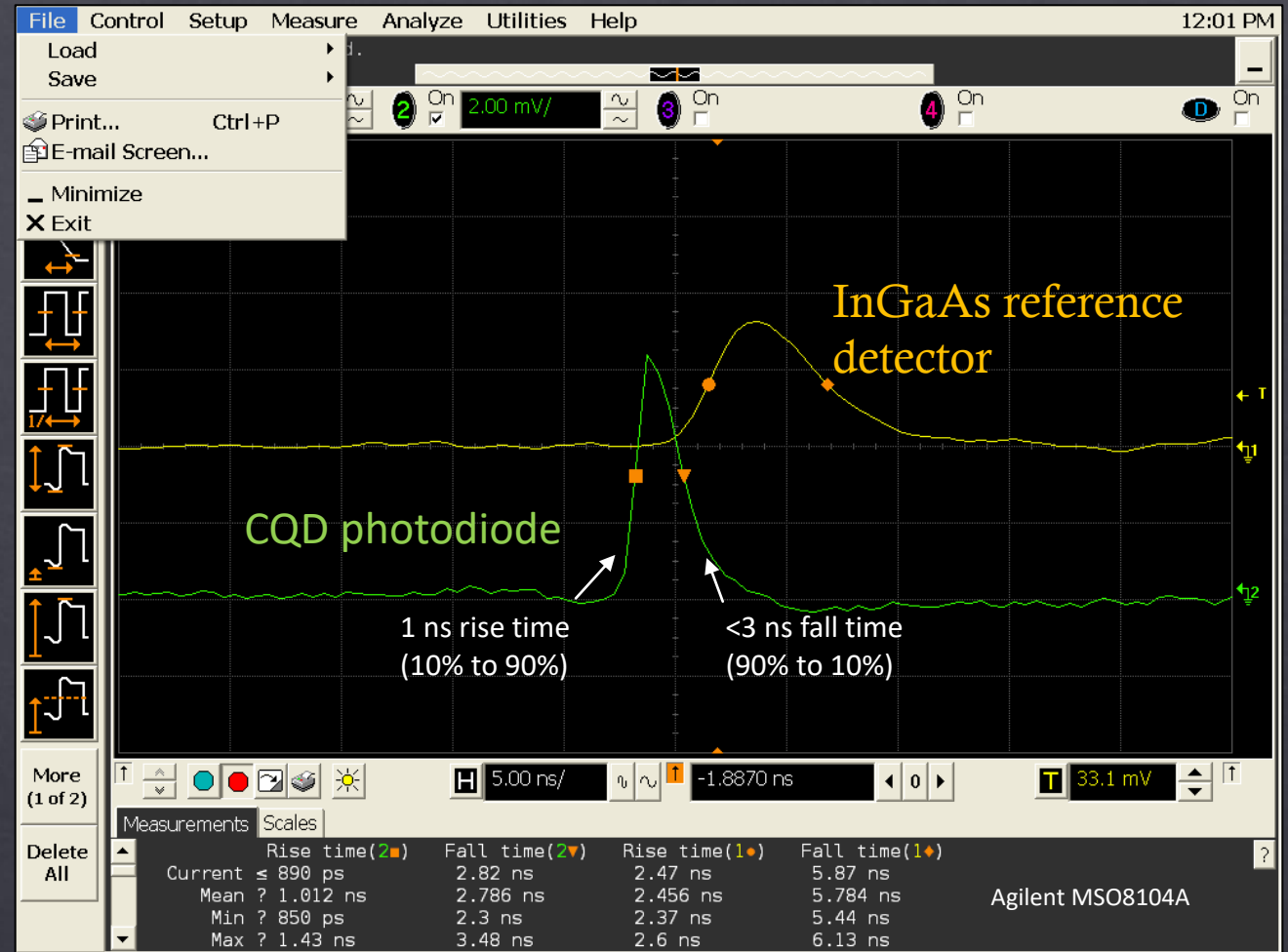
### SWIR Vision Systems CQD photodiode:

- 200  $\mu\text{m}$  x 200  $\mu\text{m}$  pixel size
- 15 pF measured capacitance (using LCR meter)
- 400 nm to 1600 nm spectral response
- Dark current density: 5 nA/cm<sup>2</sup> @25 C

### Reference photodiode:

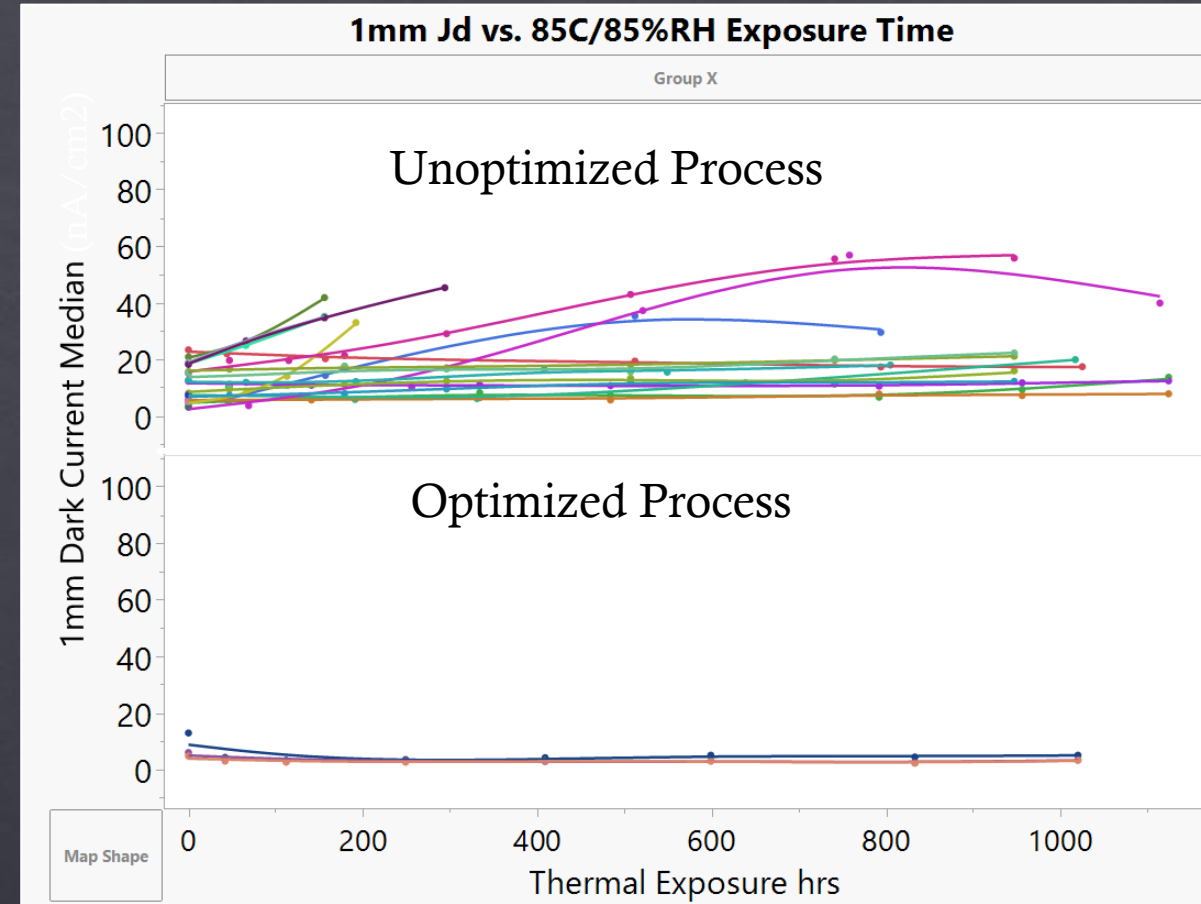
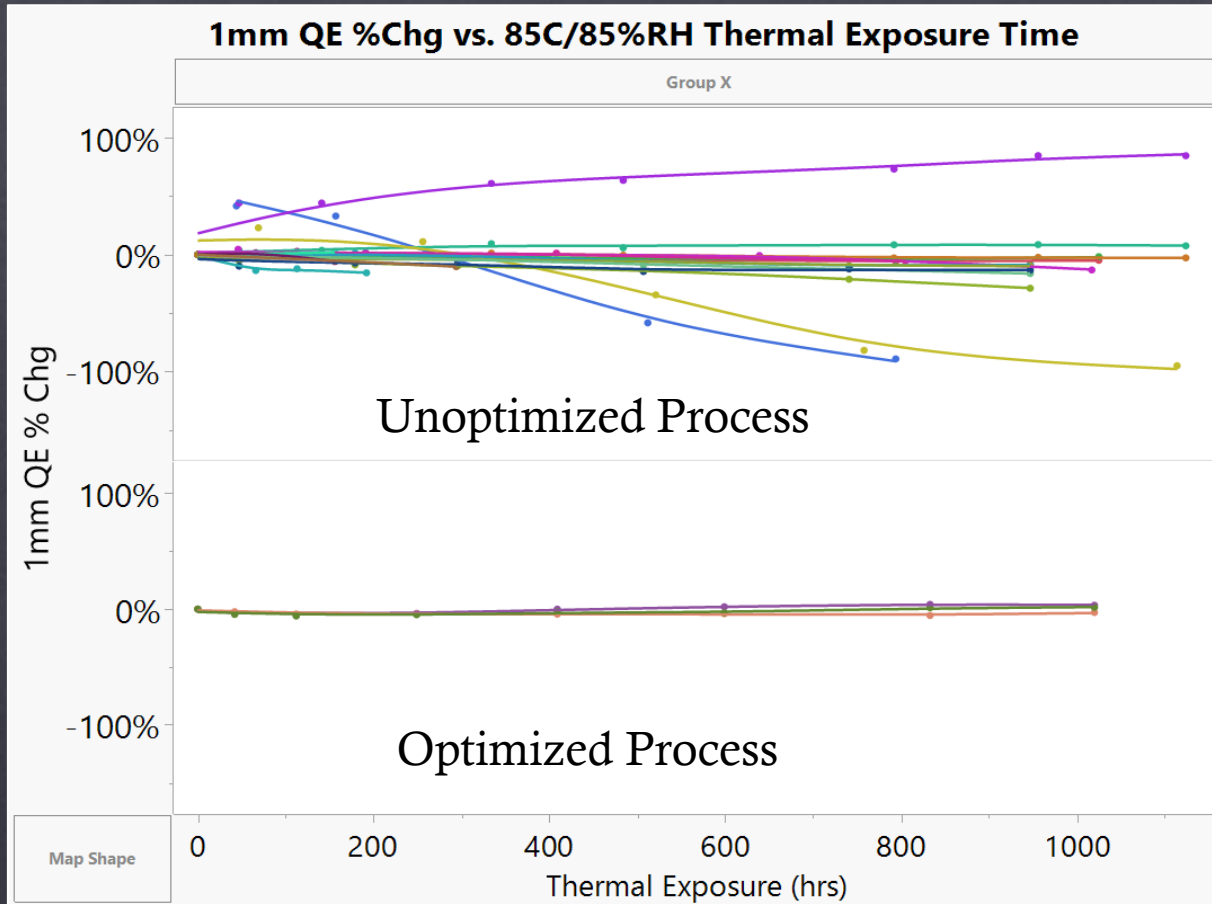
- Thorlabs FGA015 InGaAs
- 150  $\mu\text{m}$  diameter
- 2 pF capacitance (from datasheet)

Nd:YAG pulsed Laser, 1064 nm, 5 Hz rep rate



CQD's sub 5 ns rise/fall times are more than sufficient for typical laser pulse detection (LPD) applications

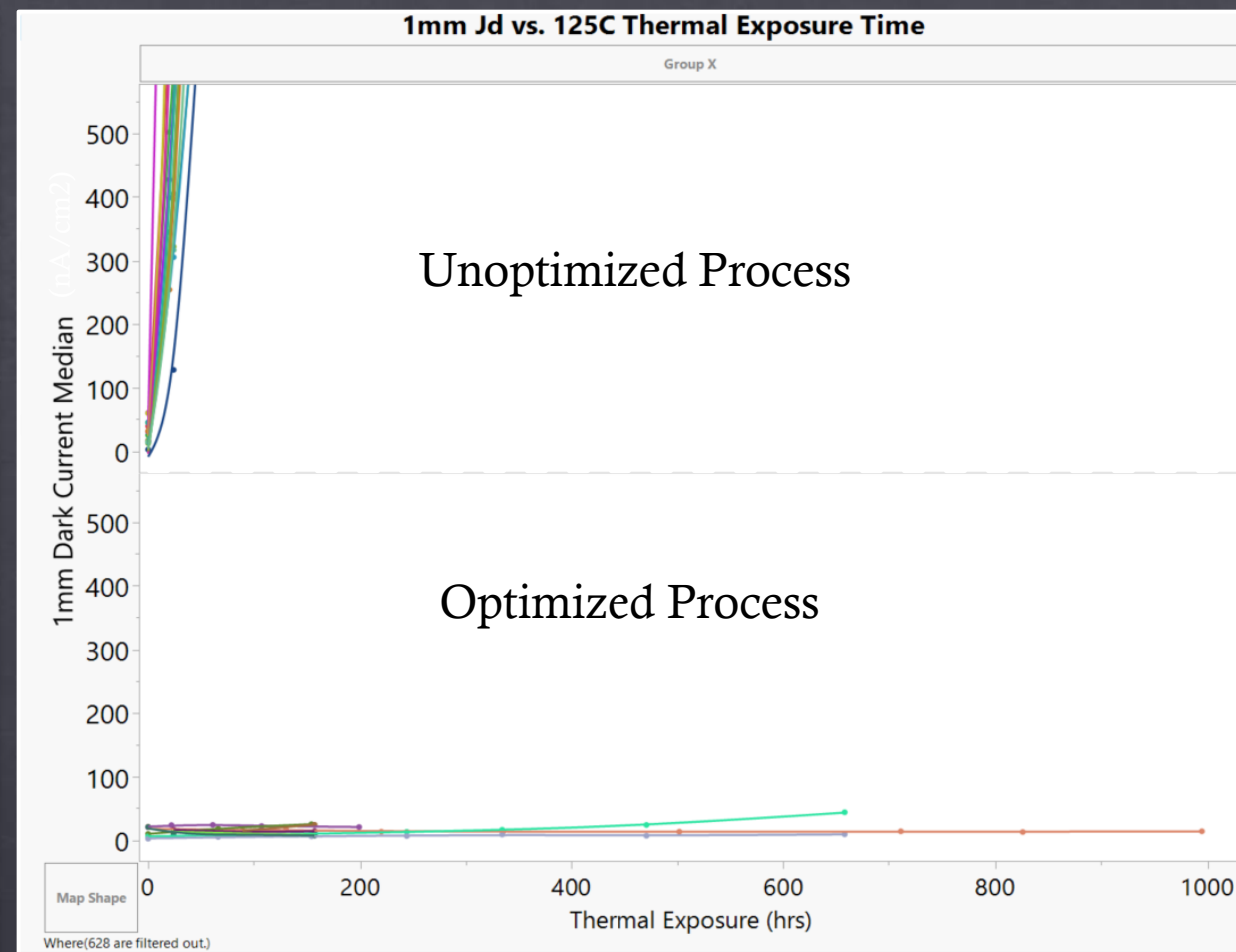
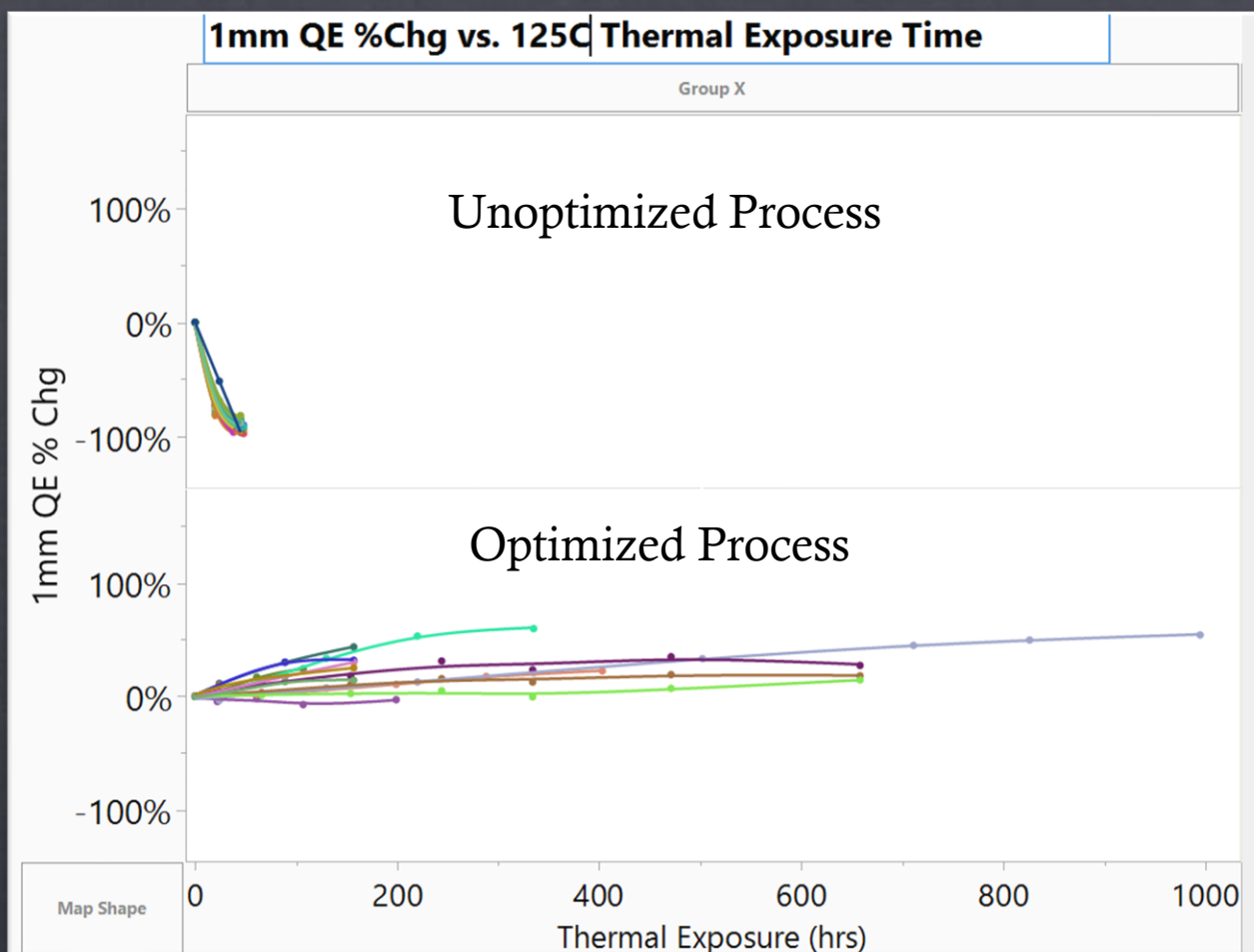
# Are CQD Detectors Reliable Enough for Field Use?



*QE% change and Jd vs 85C/85%RH stress time. Each line represents a separate passive substrate. Four 1mm x 1mm diodes measured on each substrate. Median value of the four diodes is reported.*

**CQD Detectors now survive 85C/85%RH 1000 hr accelerated stress test**

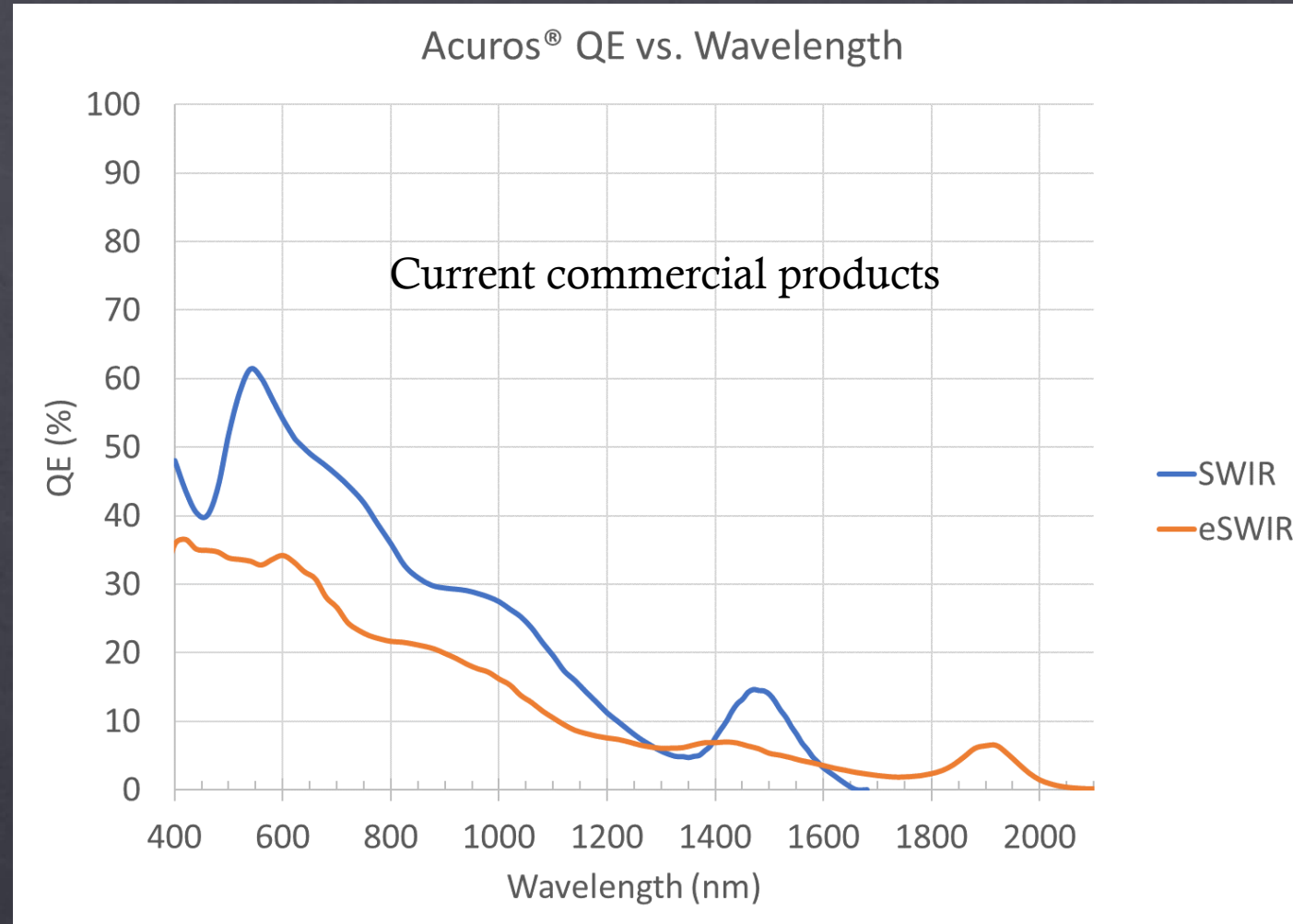
# Are CQD Detectors Reliable Enough for Field Use?



*QE% change and Jd vs 125C stress time. Each line represents a separate passive substrate. Four 1mm x 1mm diodes measured on each substrate. Median value of the four diodes is reported.*

**CQD Detectors now survive 125C 1000 hr accelerated stress test**

# Are CQD Detectors Sensitive Enough for LPD Applications?



CQD detectors have lower QE. Is existing QE “good enough” for LPD applications?

# Experimental Setup – High Level Description



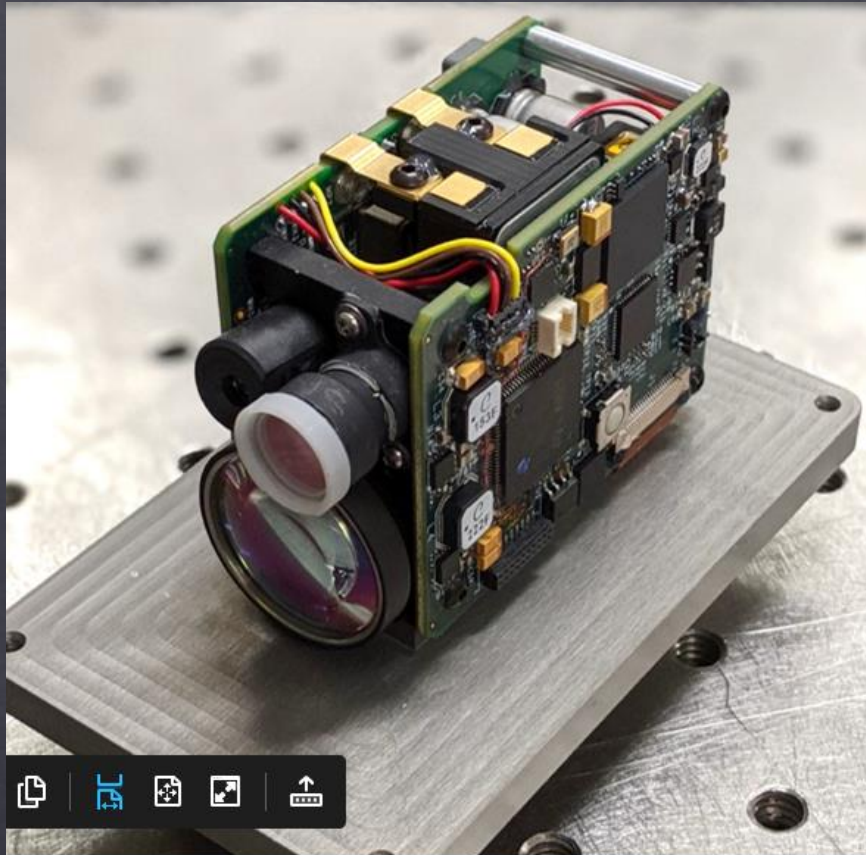
Laser source



CQD camera

Range





- 1.535  $\mu\text{m}$ , 5 mJ, laser range finder / marker
- 15 ns pulse width
- 5 hz rep rate



Target	Description	Range (m)	Size	Reflectivity
1	NATO target	200 m	2.4 x 2.4 m	~10%
2	NATO target	1000 m	2.4 x 2.4 m	~ 10%
3	Tank	1800 m	Tank	30-40%
4	NATO target	2000 m	2.4 x 2.4 m	~10%

# Experimental Setup – Acuros Camera



Camera = Acuros 1920 GigE 001

Exposure time = 0.5 ms

Gain mode = high gain (25Ke-)

Lens = 100 mm f/2.1 SWIR coated

Filter = 1535 nm band-pass filter, >60% transmission, 10 nm FWHM

ALPD = No – existing ROIC does not have ALPD capability

External trigger = Yes – synched with laser

TEC Temp = 10C





Acuros Camera can detect LRF at 200 meters

# Results – 1000 Meter - NATO Target



Acuros Camera can detect LRF at 1000 meters



Acuros Camera can detect LRF at 1800 meters



Acuros Camera can detect LRF at 2000 meters

# CQD and InGaAs Comparison



Camera	Lens	Exposure time	Filter	FOV (@ 200 m)	Pixels on target
CQD Acuros (1920 x 1080)	100 mm f/2.1	0.5 ms	1535 BP filter	1.8 km <sup>2</sup>	6,400
InGaAs (640 x 512)	83 mm f/2.6	0.5 ms	None (ALPD- capable)	0.4 km <sup>2</sup>	4,444